

Electronics

Amplifier, Power, 10W 8.5—10.5 GHz

Features

- 10 Watt CW Saturated Output Power Level
- Variable Drain Voltage (8-10V) Operation
- ◆ GaAs MSAG[™] Process
- Proven Manufacturability and Reliability
 - No Airbridges
 - Polyimide Scratch Protection
 - No Hydrogen Poisoning Susceptibility

Description

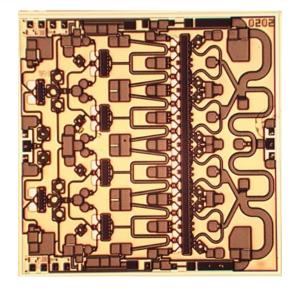
The MA08509D is a 3-stage 10 W power amplifier with on-chip bias networks. This product is fully matched to 50 ohms on both the input and output.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG[™]) Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG[™] process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



MA08509D Rev A Preliminary Information



Primary Applications

- Weather Radar
- Airborne Radar

Also Available in:

| Description | Sample Board (Die) | Die on Pedestal | Mechanical Sample (Die) | |
|-------------|--------------------|--------------------|-------------------------|--|
| Part Number | MAAP-008509-SMB004 | MAAP-008509-PED000 | MAAP-008509-MCH000 | |

Electrical Characteristics: On-Wafer, $Z_0 = 50\Omega$, $V_{DD} = 10V$, $V_{GG} = -4V$, $P_{in} = 18$ dBm

| Parameter | Symbol | Minimum | Typical | Maximum | Units |
|-------------------------|--------|---------|---------|---------|-------|
| Bandwidth | f | 8.5 | | 10.5 | GHz |
| Saturated Output Power | POUT | 39.0 | 41.0 | | dBm |
| Power Added Efficiency | PAE | 25 | 32 | | % |
| Small Signal Gain | G | 24 | 27 | | dB |
| Input VSWR | VSWR | | 2.5:1 | 4:1 | |
| Quiescent Gate Current | IGQ | 8 | 20 | 26 | mA |
| Quiescent Drain Current | IDQ | 1.3 | 2.0 | 2.5 | А |
| Drain Current @ 10 GHz | IDD | | 3.9 | 4.5 | А |
| Harmonics | 2f, 3f | | < -30 | | dBc |

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• Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

• Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

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Maximum CW Operating Conditions¹

| Parameter | Symbol | Absolute Maximum | Units |
|---------------------------------------|-------------------|------------------|-------|
| Input Power | P _{IN} | 24.0 | dBm |
| Drain Supply Voltage | V _{DD} | +12.0 | V |
| Gate Supply Voltage | V _{GG} | -6.0 | V |
| Quiescent Drain Current (No RF) | I _{DQ} | 2.7 | А |
| Quiescent DC Power Dissipated (No RF) | P _{DISS} | 27 | W |
| Junction Temperature | TJ | 170 | C° |
| Storage Temperature | T _{STG} | -55 to +150 | C° |

1. Operation beyond these limits may result in permanent damage to the part.

Recommended Operating Conditions²

| Characteristic | Symbol | Min | Тур | Мах | Unit |
|-----------------------|-----------------|------|------|--------|------|
| Drain Voltage | V _{DD} | 8.0 | 10.0 | 10.0 | V |
| Gate Voltage | V _{GG} | -4.4 | -4.0 | -3.6 | V |
| Input Power | P _{IN} | | 18.0 | 20.0 | dBm |
| MMIC Base Temperature | Т _в | | | Note 3 | °C |

2. Operation outside of these ranges may reduce product reliability.

3. Maximum MMIC Base Temperature = $170^{\circ}C - \Theta_{JC} * V_{DD} * I_{DQ}$

Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply V_{GG} = -4 V, V_{DD} = 0 V.
- 2. Ramp V_{DD} to desired voltage, typically 10 V.
- 3. Adjust V_{GG} to set I_{DQ} , (approximately @ -4 V).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn gate voltage off last.



Static-Sensitive Devices Handling Precautions Required

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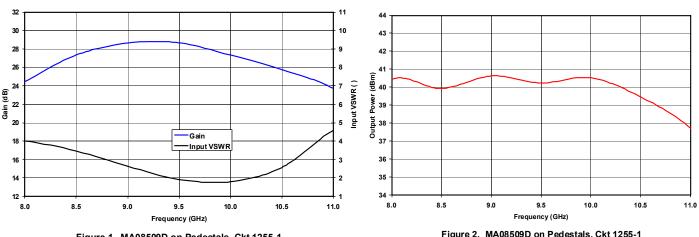


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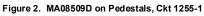


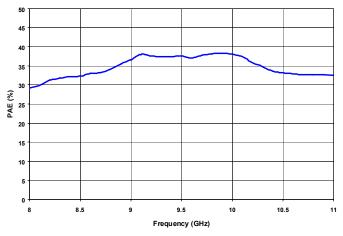
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MA08509D Rev A **Preliminary Information**











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Visit www.macom.com for additional data sheets and product information.

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Mechanical Information

Chip Size: 4.58 x 4.58 x 0.075 mm (181 x 181 x 3 mils)

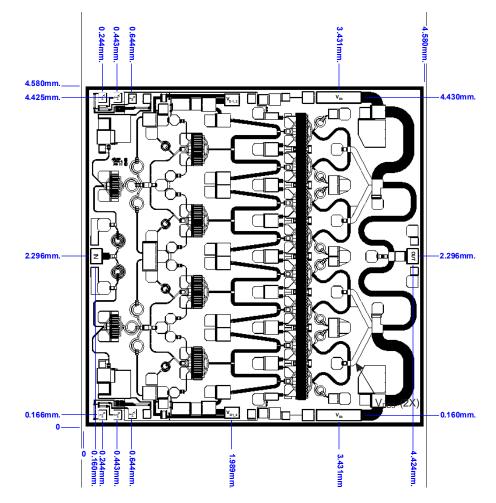


Figure 4. Die Layout

Bond Pad Information

| Ded | Turne | | Size | |
|---------------------|-------|-----------------|-----------|--------|
| Pad | Туре | Nominal Voltage | (mm) | (mils) |
| IN, OUT | RF | N/A | 150 x 200 | 6 x 8 |
| V _{DD 1/2} | DC | 10.0 V | 200 x 150 | 8 x 6 |
| V _{DD 3} | DC | 10.0 V | 400 x 150 | 16 x 6 |
| V _{GG} | DC | -4.0 V | 150 x 150 | 6 x 6 |

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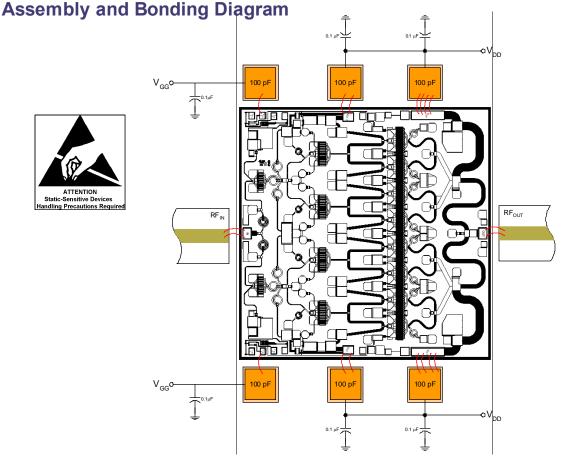


Figure 5. Recommended bonding diagram for pedestal mount. Support circuitry typical of MMIC characterization fixture for CW testing.

NOTE: Indicated Gate voltage pad (VGG 2) represents the nominal bias condition. However, the device current can be increased or decreased as required by bonding to either VGG 1 or VGG 3 (respectively).

Assembly Instructions:

Die attach: Use AuSn (80/20) 1 mil. preform solder. Limit time @ 310 °C to less than 7 minutes. Refer to Application Note AN3017 for more detailed information.

Wirebonding: Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

Biasing Note: Must apply negative bias to V_{GG} before applying positive bias to V_{DD} to prevent damage to amplifier.



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